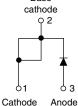


Ultrafast Rectifier, 8 A FRED Pt®





175 °C

TO-220AC

Single die

TO-220AC

PRODUCT SUMMARY

T_J max.

Package

Diode variation

Base

FEATURES

- · Ultrafast and soft recovery time
- · Optimized forward voltage drop
- Polyimide passivation
- 175 °C maximum operating junction temperature
- Rugged design
- · Good thermal performance
- Meets JESD 201 class 2 whisker test

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





RoHS HALOGEN FREE

i iiozoo i oommaiii				
I _{F(AV)}	8 A			
V_{R}	1200 V			
V _F at I _F at 125 °C	1.95 V			
t _{rr} typ.	42 ns			

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized forward voltage drop, ultrafast recovery time, and soft recovery. Polyimide passivated with a planar structure and platinum doped life time control guarantee ruggedness, reliability, and offer a solid value for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery chargers, inverters for solar inverters or as freewheeling diodes in motor drives.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 140 °C, D = 0.50	8				
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	80	Α			
Repetitive peak forward current	I _{FRM}		16				
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 200 μΑ	1200	-	-			
Forward voltage	V _F	I _F = 8 A	-	2.05	2.55	V		
	VF	I _F = 8 A, T _J = 125 °C	-	1.95	2.37			
5		V _R = V _R rated	-	-	55			
Reverse leakage current	I _R	$T_J = 125$ °C, $V_R = V_R$ rated		100	μA			
Junction capacitance	C _T	V _R = 200 V	-	8	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 1.0 \text{ A}$	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{A}, V_R = 30 \text{ V}$		42	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A dI _F /dt = 100 A/μs V _R = 390 V	-	144	-	ns	
		T _J = 125 °C		-	204	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	5	-	А	
		T _J = 125 °C		-	7.2	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	370	-	nC	
		T _J = 125 °C		-	745	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	1.25	1.5			
Thermal resistance, junction to case	R _{thJA}	Typical socket mount	-	54	60	°C/W		
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.18	0.4			
Weight			-	0.2	-	g		
weight			-	0.07	-	oz.		
Mounting torque			6.0	_	12	kgf · cm		
			(5.0)		(10)	(lbf · in)		
Marking device		Case style TO-220AC	8ETU12					

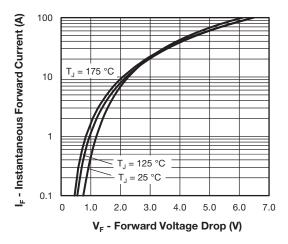


Fig. 1 - Typical Forward Voltage Drop Characteristics

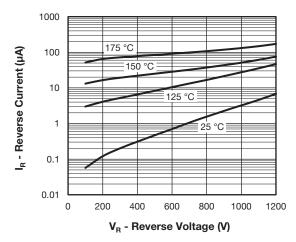


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



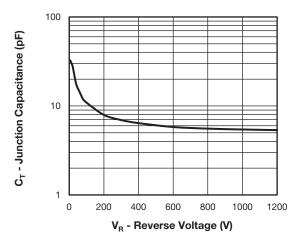


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

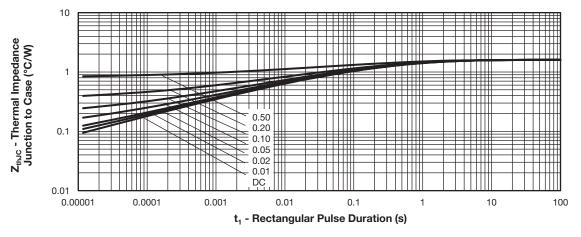


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

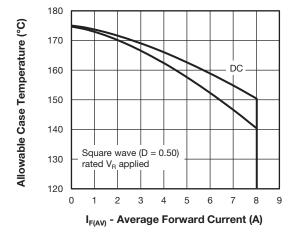


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

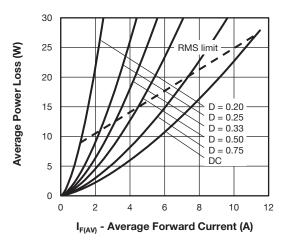


Fig. 6 - Forward Power Loss Characteristics



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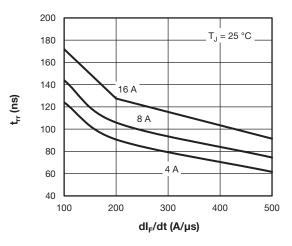


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

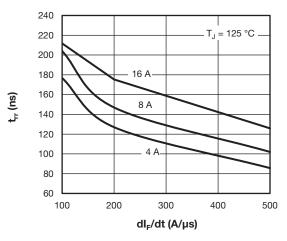


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt

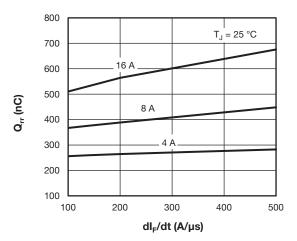


Fig. 9 - Typical Stored Charge vs. dl_F/dt

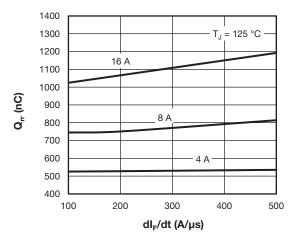


Fig. 10 - Typical Stored Charge vs. dl_F/dt

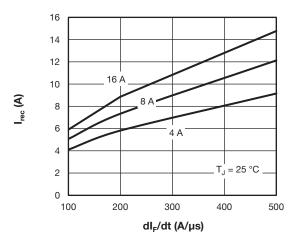


Fig. 11 - Typical Reverse Current vs. dI_F/dt

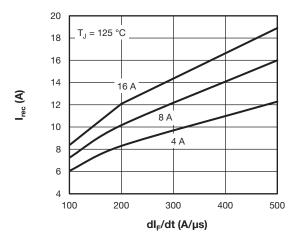
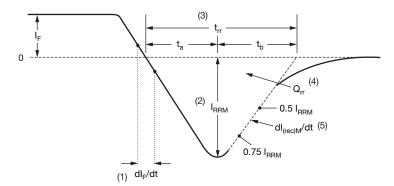


Fig. 12 - Typical Reverse Current vs. dl_F/dt

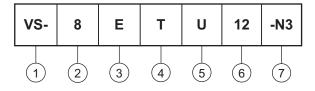


- (1) dl_F/dt rate of change of current through zero crossing
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}
- (2) I_{RBM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RBM} and 0.50 I_{RBM} extrapolated to zero current.
- (5) dl_{(rec)M}/dt peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating (8 = 8 A)
- 3 E = single diode
- 4 Package:

T = TO-220

- 5 U = ultrafast recovery
- 6 Voltage rating (12 = 1200 V)
- 7 Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

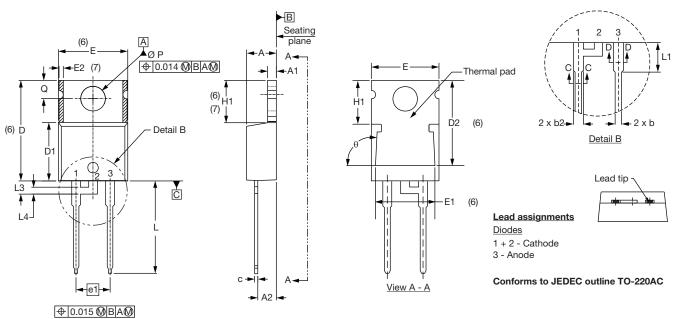
ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-8ETU12-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95221				
Part marking information	www.vishay.com/doc?95068				



TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL MILLIMETERS INCH		HES	NOTES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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Revision: 13-Jun-16 1 Document Number: 91000